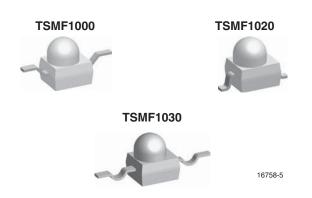
TSMF1000, TSMF1020, TSMF1030

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RoHS

COMPLIANT

High Speed Infrared Emitting Diode, RoHS Compliant, 890 nm, GaAlAs Double Hetero



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DESCRIPTION

TSMF1000 series are infrared, 890 nm emitting diodes in GaAlAs double hetero (DH) technology with high radiant power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

FEATURES

- Package type: surface mount
- · Package form: GW, RGW, yoke, axial
- Dimensions (L x W x H in mm): 2.5 x 2 x 2.7
- Peak wavelength: λ_p = 890 nm
- · High radiant power
- Angle of half intensity: $\varphi = \pm 17^{\circ}$
- · Low forward voltage
- Suitable for high pulse current operation
- · Versatile terminal configurations
- Package matches with detector TEMD1000
- Floor life: 168 h, MSL 3, acc. J-STD-020
- Compliant to RoHS Directive 2002/95/EC and in accordance with WEEE 2002/96/EC

APPLICATIONS

- IrDA compatible data transmission
- Miniature light barrier
- Photointerrupters
- Optical switch
- Control and drive circuits
- Shaft encoders

PRODUCT SUMMARY				
COMPONENT	I _e (mW/sr)	φ (deg)	λ _P (nm)	t _r (ns)
TSMF1000	5	± 17	890	30
TSMF1020	5	± 17	890	30
TSMF1030	5	± 17	890	30

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
TSMF1000	Tape and reel	MOQ: 1000 pcs, 1000 pcs/reel	Reverse gullwing		
TSMF1020	Tape and reel	MOQ: 1000 pcs, 1000 pcs/reel	Gullwing		
TSMF1030	Tape and reel	MOQ: 1000 pcs, 1000 pcs/reel	Yoke		

Note

MOQ: minimum order quantity



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	5	V	
Forward current		I _F	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	200	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	0.8	А	
Power dissipation		Pv	180	mW	
Junction temperature		Тj	100	°C	
Operating temperature range		T _{amb}	- 40 to + 85	°C	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Soldering temperature	t ≤ 5 s	T _{sd}	260	°C	
Thermal resistance junction/ambient	Soldered on PCB, pad dimensions: 4 mm x 4 mm	R _{thJA}	400	K/W	

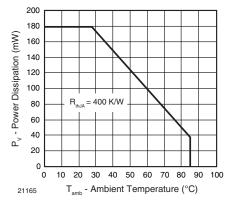


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

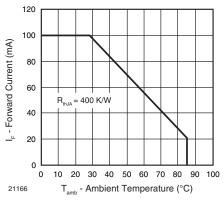


Fig. 2 - Forward Current Limit vs. Ambient Temperature

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 20 mA	V _F		1.3	1.5	V
	I _F = 1 A, t _p = 100 μs	V _F		2.4		V
Temperature coefficient of V_F	I _F = 1 mA	TK _{VF}		- 1.8		mV/K
Reverse current	V _R = 5 V	I _R			10	μA
Junction capacitance	$V_{R} = 0 V, f = 1 MHz, E = 0$	Cj		160		pF
Radiant intensity	I _F = 20 mA	l _e	2.5	5	13	mW/sr
	$I_F = 100 \text{ mA}, t_p = 100 \mu\text{s}$	l _e		25		mW/sr
Radiant power	l _F = 100 mA, t _p = 20 ms	φe		35		mW
Temperature coefficient of ϕ_{e}	I _F = 20 mA	TKφ _e		- 0.6		%/K
Angle of half intensity		φ		± 17		deg
Peak wavelength	I _F = 20 mA	λρ		890		nm
Spectral bandwidth	I _F = 20 mA	Δλ		40		nm
Temperature coefficient of λ_p	I _F = 20 mA	ΤΚλρ		0.2		nm/K
Rise time	I _F = 20 mA	tr		30		ns
Fall time	I _F = 20 mA	t _f		30		ns
Cut-off frequency	$I_{DC} = 70 \text{ mA}, I_{AC} = 30 \text{ mA pp}$	f _c		12		MHz
Virtual source diameter		d		1.2		mm

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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

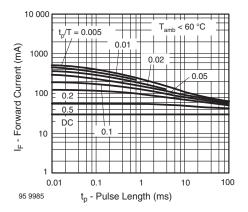


Fig. 3 - Pulse Forward Current vs. Pulse Duration

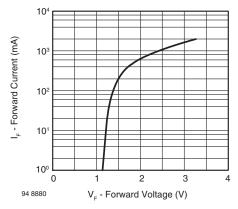


Fig. 4 - Forward Current vs. Forward Voltage

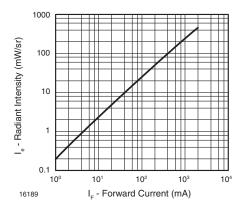


Fig. 5 - Radiant Intensity vs. Forward Current

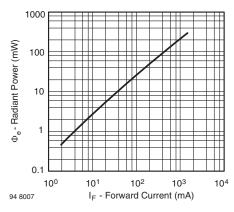


Fig. 6 - Radiant Power vs. Forward Current

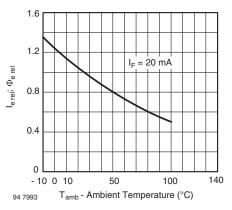


Fig. 7 - Rel. Radiant Intensity/Power vs. Ambient Temperature

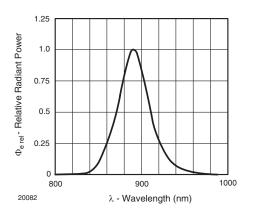


Fig. 8 - Relative Radiant Power vs. Wavelength

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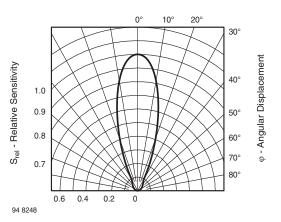


Fig. 9 - Relative Radiant Intensity vs. Angular Displacement

PRECAUTIONS FOR USE

1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (burn out will happen).

2. Storage

- Storage temperature and rel. humidity conditions are: 5 °C to 35 °C, R.H. 60 %.
- Floor life must not exceed 168 h, acc. to JEDEC level 3, J-STD-020.

Once the package is opened, the products should be used within a week. Otherwise, they should be kept in a damp proof box with desiccant.

Considering tape life, we suggest to use products within one year from production date.

- If opened more than one week in an atmosphere 5 °C to 35 °C, R.H. 60 %, devices should be treated at 60 °C \pm 5 °C for 15 h.
- If humidity indicator in the package shows pink color (normal blue), then devices should be treated with the same conditions as 2.3.

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REFLOW SOLDER PROFILE

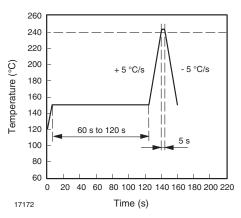
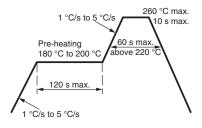


Fig. 10 - Lead Tin (SnPb) Reflow Solder Profile



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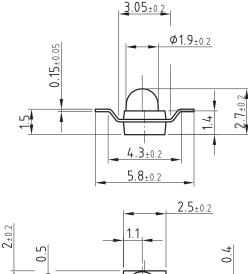
Fig. 11 - Lead (Pb)-Free Reflow Solder Profile acc. J-STD-020

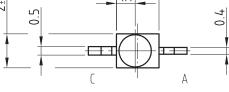
4





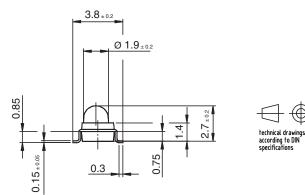
PACKAGE DIMENSIONS in millimeters: TSMF1000



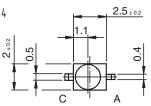


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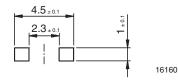
PACKAGE DIMENSIONS in millimeters: TSMF1020



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Solder pad proposal

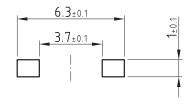




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technical drawings according to DIN specifications

Solder pad proposal



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5 For technical questions, contact: emittertechsupport@vishay.com Document Number: 81061

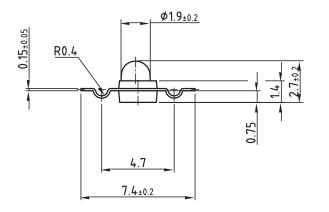
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TSMF1000, TSMF1020, TSMF1030

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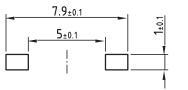
PACKAGE DIMENSIONS in millimeters: TSMF1030



Drawing-No.: 6.544-5329.01-4 Issue: 4; 08.05.03

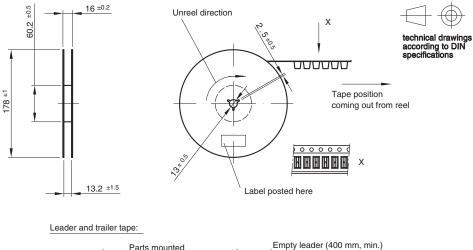


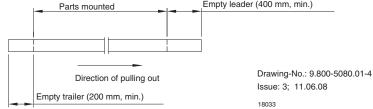
Solder pad proposal



16228

REEL DIMENSIONS in millimeters



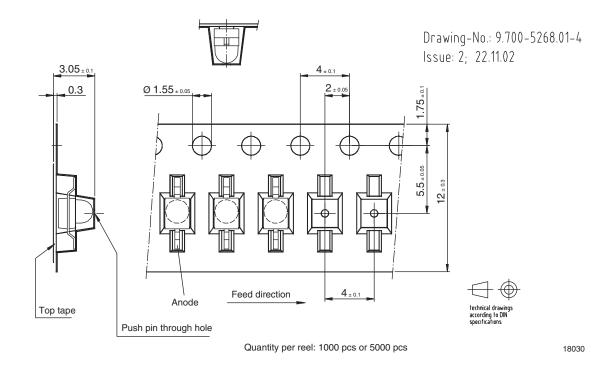


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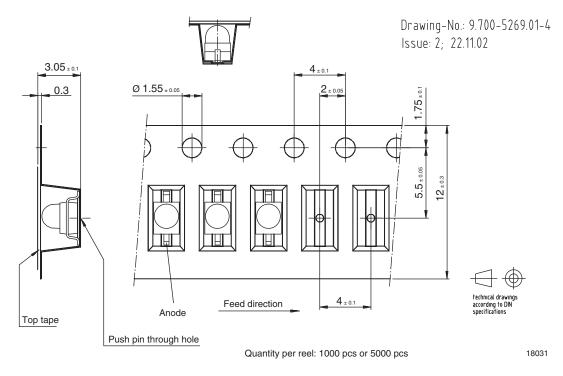


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TAPING DIMENSIONS in millimeters: TSMF1000



TAPING DIMENSIONS in millimeters: TSMF1020



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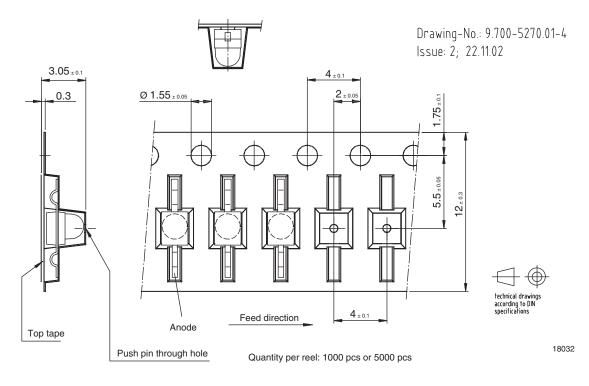
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TAPING DIMENSIONS in millimeters: TSMF1030





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